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APPLICANT:

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GROUP ART  
UNIT:

1765

## U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Date	Name	Class	Subclass	Filing Date if Appropriate
SA	A	5,363,398	11/1994	Glass et al.	372	92	
SA	B	5,374,564	12/1994	Bruel -	437	24	
	C						
	D						
	E						
	F						
	G						
	H						

## FOREIGN PATENT DOCUMENTS

		Document No.	Date	Country	Class	Subclass	Translation
SA	I	0 578 407	1/1994	European			English text
	J						
	K						

## OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

SA	L	Yukari Ishikawa et al. EPITAXY-READY Si/SiO <sub>2</sub> BRAGG REFLECTORS BY MULTIPLE SEPARATION-BY-IMPLANTED-OXYGEN. 16 December 1996. Pgs. 3881-3883.
	M	E. F. Schubert et al. GIANT ENHANCEMENT OF LUMINESCENCE INTENSITY IN Er-DOPED Si/SiO <sub>2</sub> RESONANT CAVITIES. 21 September 1992. Pgs. 1381-1383.
	N	R. A. Soref et al. SILICON INTERSUBBAND LASERS. 1998. Pgs. 427-439.
	O	Richard A. Soref. PROSPECTS FOR NOVEL Si-BASED OPTOELECTRONIC DEVICES: UNIPOLAR AND p-i-p-i lasers. July 1992. Pgs 325-329.
SA	P	Michio Tajima et al. LUMINESCENCE DUE TO ELECTRON-HOLE CONDENSATION IN SILICON-ON-INSULATOR. August 1998. Pgs. 2224-2228.
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Examiner:	Shamim Ahmed	Date Considered
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